

MN54ACQ573-X REV 1A0

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Octal D-Type Latch With TRI-State Outputs

General Description

The ACQ573 is a high speed octal latch with buffered common Latch Enable (LE) and buffered common Output Enable (OE) inputs.

The 'ACQ' is functionally identical to the ACQ373 but with inputs and outputs on opposite sides of the package.

The 'ACQ' utilizes NSC Quiet Series technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series TM features GT0 TM output control and undershoot corrector in addition to a split ground bus for superior performance.

Industry Part Number

54ACQ573

Prime Die

E573

NS Part Numbers

 54ACQ573DMQB
 54ACQ573FMQB
 54ACQ573LMQB

Processing

MIL-STD-883, Method 5004

Quality Conformance Inspection

MIL-STD-883, Method 5005

Subgrp	Description	Temp (°C)
1	Static tests at	+25 C
2	Static tests at	+125 C
3	Static tests at	-55 C
4	Dynamic tests at	+25 C
5	Dynamic tests at	+125 C
6	Dynamic tests at	-55 C
7	Functional tests at	+25 C
8A	Functional tests at	+125 C
8B	Functional tests at	-55 C
9	Switching tests at	+25 C
10	Switching tests at	+125 C
11	Switching tests at	-55 C

Features

- Icc and Ioz reduced by 50%
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Improved latch-up immunity
- Inputs and outputs on opposite sides of package allow easy interface with

microprocessors
- Outputs source /sink 24 mA
- Faster prop delay than standard 'ACT573
- 4kV minimum ESD immunity
- Standard Military Drawing (SMD)
 - ACQ: 5962-92180

(Absolute Maximum Ratings)

(Note 1)

Supply Voltage (Vcc)	-0.5V to +7.0V
DC Input Diode Voltage (Vi)	-0.5V to Vcc +0.5V
DC Output Diode Current (Iok)	
Vo = -0.5V	-20 mA
Vo = Vcc +0.5V	+20 mA
DC Output Voltage (Vo)	-0.5V to Vcc +0.5V
DC Output Source or Sink Current (Io)	±50 mA
DC Vcc or Ground Current per Output Pin (Icc or Ignd)	±50 mA
Storage Temperature (Tstg)	-65 C to +150 C
DC Latchup Source or Sink Current	±300 mA
Junction Temperature (Tj)	
CDIP	175 C

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specification should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/ input loading variables. Nationaldoes not recommend operation FACT TM circuits outside databook specifications.

Recommended Operating Conditions

(Note 1)

Supply Voltage (Vcc)	2.0V to 6.0V
Input Voltage (Vi)	0V to Vcc
Output Voltage (Vo)	0V to Vcc
Operating Temperature (Ta)	-55 C to +125 C
Minimum Input Edge Rate Delta V/Delta t	
ACQ Devices	
Vin from 30% to 70% of Vcc	
Vcc @ 3.0V, 4.5V, 5.5V	125 mV/ns

Note 1: All commercial packaging is not recommended for applications requiring greater than 2000 temperature cycles from -40 C to + 125 C

Electrical Characteristics

DC PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)

DC: VCC 3.0V to 5.5V, Temperature Range: -55C to 125C. NOTE: -55C TEMPERATURE, SUBGROUP 3 IS GUARANTEED BUT NOT TESTED.

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
IIH	High Level input current	VCC=5.5V, VM=5.5V	1, 2	INPUT		0.1	uA	1
			1, 2	INPUT		1.0	uA	2, 3
IIL	Low level input current	VCC=5.5V, VM=0.0V	1, 2	INPUT		-0.1	uA	1
			1, 2	INPUT		-1.0	uA	2, 3
VOL	Low level output voltage	VCC=3.0V, VIH=2.1V, VIL=0.9V, IOL=50.0uA	1, 2	OUTPUT		.10	V	1, 2, 3
		VCC=4.5V, VIH=3.15V, VIL=1.35V, IOL=50.0uA	1, 2	OUTPUT		.10	V	1, 2, 3
		VCC=5.5V, VIH=3.85V, VIL=1.65V, IOL=50.0uA	1, 2	OUTPUT		.10	V	1, 2, 3
		VCC=3.0V, VIH=2.1V, VIL=0.9V, IOL=12.0mA	1, 2	OUTPUT		.36	V	1
			1, 2	OUTPUT		.50	V	2, 3
		VCC=4.5V, VIH=3.15V, VIL=1.35V, IOL=24.0mA	1, 2	OUTPUT		.36	V	1
			1, 2	OUTPUT		.50	V	2, 3
		VCC=5.5V, VIH=3.85V, VIL=1.65V, IOL=24.0mA	1, 2	OUTPUT		.36	V	1
			1, 2	OUTPUT		.50	V	2, 3
VIOL	Dynamic Output Current Low	VCC=5.5V, VIL=0.0V, VIH=5.5V, IOL=50.0mA	1, 2, 5	OUTPUT		1.65	V	1, 2, 3
VOH	High Level Output Voltage	VCC=3.0V, VIL=0.9V, VIH=2.1V, IOH=-50.0uA	1, 2	OUTPUT	2.90		V	1, 2, 3
		VCC=4.5V, VIL=1.35V, VIH=3.15V, IOH=-50uA	1, 2	OUTPUT	4.40		V	1, 2, 3
		VCC=5.5V, VIL=1.65V, VIH=3.85V, IOH=-50uA	1, 2	OUTPUT	5.40		V	1, 2, 3
		VCC=3.0V, VIL=0.9V, VIH=2.1V, IOH=-12.0mA	1, 2	OUTPUT	2.56		V	1
			1, 2	OUTPUT	2.40		V	2, 3
		VCC=4.5V, VIL=1.35V, VIH=3.15V, IOH=-24.0mA	1, 2	OUTPUT	3.86		V	1
			1, 2	OUTPUT	3.70		V	2, 3
		VCC=5.5V, VIL=1.65V, VIH=3.85V, IOH=-24.0mA	1, 2	OUTPUT	4.86		V	1
			1, 2	OUTPUT	4.70		V	2, 3
VI0H	Dynamic Output current High	VCC=5.5V, VINH=5.5V, VIH=5.5V, VIL=0.0V, IOH=-50.0mA	1, 2, 5	OUTPUT	3.85		V	1, 2, 3
ICCH	Positive Supply Current	VCC=5.5V	1, 2	VCC		4.0	uA	1
			1, 2	VCC		80	uA	2, 3

Electrical Characteristics

DC PARAMETERS(Continued)

(The following conditions apply to all the following parameters, unless otherwise specified.)

DC: VCC 3.0V to 5.5V, Temperature Range: -55C to 125C. NOTE: -55C TEMPERATURE, SUBGROUP 3 IS GUARANTEED BUT NOT TESTED.

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
ICCL	Negative Supply Current	VCC=5.5V	1, 2	VCC		4.0	uA	1
			1, 2	VCC		80	uA	2, 3
IC CZ	High Impedance Supply Current	VCC=5.5V	1, 2	VCC		4.0	uA	1
			1, 2	VCC		80	uA	2, 3
IOZH	Maximum TRI-STATE Leakage Current High	VCC=3.0V, VIH=2.1V, VM=3.0V	1, 2	OUTPUT		0.25	uA	1
			1, 2	OUTPUT		5.0	uA	2, 3
		VCC=4.5V, VIH=3.15V, VM=4.5V	1, 2	OUTPUT		0.25	uA	1
			1, 2	OUTPUT		5.0	uA	2, 3
		VCC=5.5V, VIH=3.85V, VM=5.5V	1, 2	OUTPUT		0.25	uA	1
			1, 2	OUTPUT		5.0	uA	2, 3
IOZL	Maximum TRI-STATE Leakage Current Low	VCC=3.0V, VM=0.0V, VIH=2.1V	1, 2	OUTPUT		-0.25	uA	1
			1, 2	OUTPUT		-5.0	uA	2, 3
		VCC=4.5V, VM=0.0V, VIH=3.15V	1, 2	OUTPUT		-0.25	uA	1
			1, 2	OUTPUT		-5.0	uA	2, 3
		VCC=5.5V, VM=0.0V, VIH=3.85V	1, 2	OUTPUT		-0.25	uA	1
			1, 2	OUTPUT		-5.0	uA	2, 3
VIKL		VCC=4.5V, IKL=-18mA	1, 2	INPUT		-1.2	V	1, 2, 3
VIKH		VCC=4.5V, IKL=18mA	1, 2	INPUT		5.7	V	1, 2, 3
VILD	Maximum Low Level Dynamic Voltage	VCC=5.0V, LOAD 50pF, 500 OHMS	6, 9	INPUT		1.5	V	4
VIHD	Minimum High Level Dynamic Voltage	VCC=5.0V, LOAD 50pF, 500 OHMS	6, 9	INPUT	3.5		V	4
VOLP	Quiet Output Maximum Dynamic VOL	VCC=5.0V, LOAD 50pF, 500 OHMS	6, 8	OUTPUT		1.75	V	4
VOLV	Quiet Output Minimum Dynamic VOL	VCC=5.0V, LOAD 50pF, 500 OHMS	6, 8	OUTPUT		-1.2	V	4

Electrical Characteristics

AC PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)

AC: CL=50pf, RL=500 OHMS, TR=3.0ns, TF=3.0ns, Temp range: -55C to +125C. NOTE: -55C TEMPERATURE, SUBGROUP 11 IS GUARANTEED BUT NOT TESTED.

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
tpLH(1)	Propagation Delay	VCC=4.5V	3, 4, 7	Dn to On	1.5	9.5	ns	9
			3, 4, 7	Dn to On	1.5	11.0	ns	10, 11
tpHL(1)	Propagation Delay	VCC=4.5V	3, 4, 7	Dn to On	1.5	9.5	ns	9
			3, 4, 7	Dn to On	1.5	11.0	ns	10, 11
tpLH(2)	Propagation Delay	VCC=4.5V	3, 4, 7	LE to On	1.5	9.5	ns	9
			3, 4, 7	LE to On	1.5	11.0	ns	10, 11
tpHL(2)	Propagation Delay	VCC=4.5V	3, 4, 7	LE to On	1.5	9.5	ns	9
			3, 4, 7	LE to On	1.5	11.0	ns	10, 11
tpZH(1)	Output Enable Time	VCC=4.5V	3, 4, 7	$\overline{OE}$ to On	1.5	8.5	ns	9
			3, 4, 7	$\overline{OE}$ to On	1.5	10.0	ns	10, 11
tpZL(1)	Output Enable Time	VCC=4.5V	3, 4, 7	$\overline{OE}$ to On	1.5	8.5	ns	9
			3, 4, 7	$\overline{OE}$ to On	1.5	10.0	ns	10, 11
tpHZ(1)	Output Disable Time	VCC=4.5V	3, 4, 7	$\overline{OE}$ to On	1.0	9.5	ns	9
			3, 4, 7	$\overline{OE}$ to On	1.0	10.5	ns	10, 11
tpLZ(1)	Output Disable Time	VCC=4.5V	3, 4, 7	$\overline{OE}$ to On	1.0	9.5	ns	9
			3, 4, 7	$\overline{OE}$ to On	1.0	10.5	sn	10, 11
ts(H/L)(1)	Setup Time HIGH or LOW	VCC=4.5V	6	Dn to LE		4.0	ns	9, 10, 11
th(H/L)(1)	Hold Time HIGH or LOW	VCC=4.5V	6	Dn to LE	2.0		ns	9, 10, 11
tw(H)(1)	Pulse Width	VCC=4.5V	6	LE Pulse Width		5.0	ns	9, 10, 11

Electrical Characteristics

AC PARAMETERS(Continued)

(The following conditions apply to all the following parameters, unless otherwise specified.)

AC: CL=50pf, RL=500 OHMS, TR=3.0ns, TF=3.0ns, Temp range: -55C to +125C. NOTE: -55C TEMPERATURE, SUBGROUP 11 IS GUARANTEED BUT NOT TESTED.

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
tpLH(3)	Propagation Delay	VCC=3.0V	3, 4	Dn to On	1.5	13.0	ns	9
			3, 4	Dn to On	1.5	16.0	ns	10, 11
tpHL(3)	Propagation Delay	VCC=3.0V	3, 4	Dn to On	1.5	13.0	ns	9
			3, 4	Dn to On	1.5	16.0	ns	10, 11
tpLH(4)	Propagation Delay	VCC=4.5V	3, 4	LE to On	1.5	12.5	ns	9
			3, 4	LE to On	1.5	15.0	ns	10, 11
tpHL(4)	Propagation Delay	VCC=4.5V	3, 4	LE to On	1.5	12.5	ns	9
			3, 4	LE to On	1.5	15.0	ns	10, 11
tpZH(2)	Output Enable Time	VCC=3.0V	3, 4	OE to On	1.5	11.5	ns	9
			3, 4	OE to On	1.5	13.5	ns	10, 11
tpZL(2)	Output Enable Time	VCC=3.0V	3, 4	OE to On	1.5	11.5	ns	9
			3, 4	OE to On	1.5	13.5	ns	10, 11
tpHZ(2)	Output Disable Time	VCC=3.0V	3, 4	OE to On	1.5	11.5	ns	9
			3, 4	OE to On	1.5	13.0	ns	10, 11
tpLZ(2)	Output Disable Time	VCC=3.0V	3, 4	OE to On	1.5	11.5	ns	9
			3, 4	OE to On	1.5	13.0	ns	10, 11
ts(H/L)(2)	Setup Time HIGH or LOW	VCC=3.0V	6	Dn to LE		4.0	ns	9, 10, 11
th(H/L)(2)	Hold Time HIGH or LOW	VCC=3.0V	6	Dn to LE		2.0	ns	9, 10, 11
tw(H)(2)	Pulse Width	VCC=3.0V	6	LE Pulse Width		5.0	ns	9, 10, 11

Note 1: SCREEN TESTED 100% ON EACH DEVICE AT +25C & +125C TEMPERATURE, SUBGROUPS 1, 2, 7, & 8.

(Continued)

- Note 2: SAMPLE TESTED (METHOD 5005, TABLE 1) ON EACH MFG. LOT AT +25C & +125C TEMPERATURE, SUBGROUPS A1, 2, 7, & 8.
- Note 3: SCREEN TESTED 100% ON EACH DEVICE AT +25C TEMPERATURE ONLY, SUBGROUP A9.
- Note 4: SAMPLE TESTED (METHOD 5005, TABLE 1) ON EACH MFG. LOT AT +25C & +125C TEMPERATURE, SUBGROUPS A9 & 10.
- Note 5: TRANSMISSION LINE DRIVING TEST, GUARDBAND LIMITS SET FOR +25C, 2 MSEC DURATION MAX.
- Note 6: GUARANTEED BUT NOT TESTED (DESIGN CHARACTERIZATION DATA)
- Note 7: +25C & +125C MIN LIMITS GUARANTEED FOR 5.5V BY GUARDBANDING 4.5V MIN. LIMITS.
- Note 8: MAX NUMBER OF OUTPUTS DEFINED AS (N). DATA INPUTS ARE DRIVEN 0V TO 5V. ONE OUTPUT @ GND.
- Note 9: MAX NUMBER OF DATA INPUTS (N) SWITCHING. N-1 INPUTS SWITCHING 0V TO 5V. INPUT-UNDER-TEST SWITCHING- 5V TO THRESHOLD (VILD), 0V TO THRESHOLD (VIHD), FREQ. = 1 MHz.